

---

---

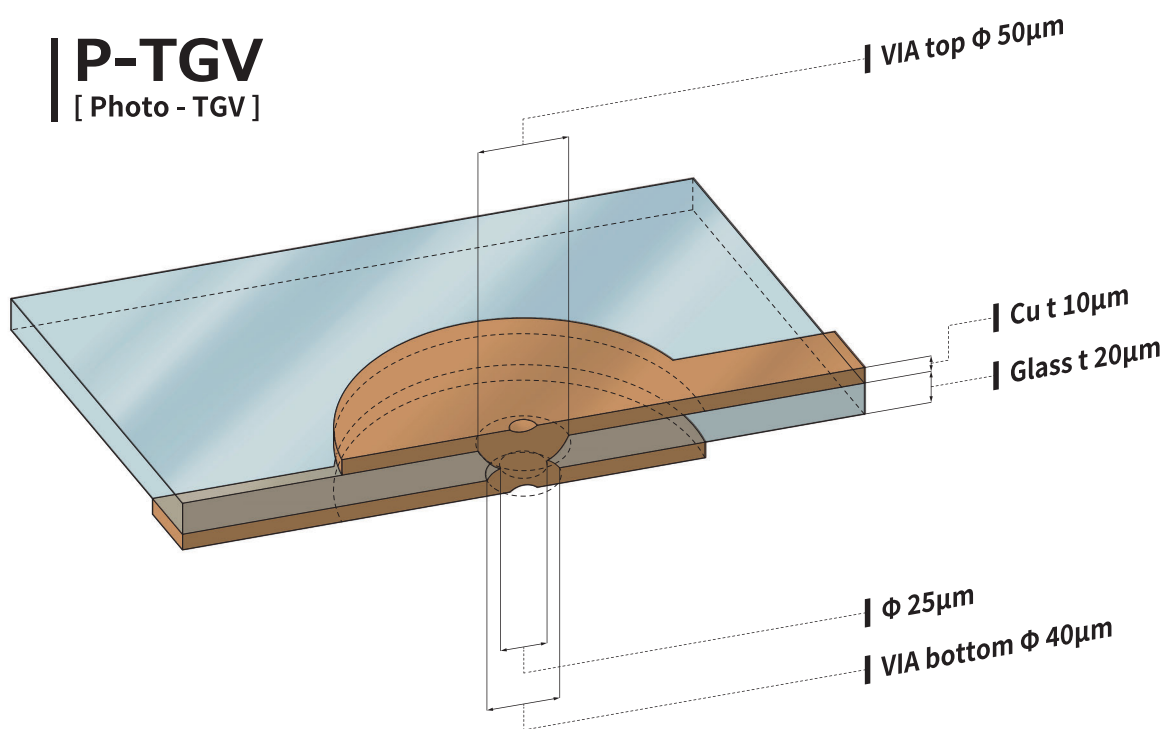
# 技術資料

## TECNICAL INFOMATION

---

---

**P-TGV**  
[ Photo - TGV ]



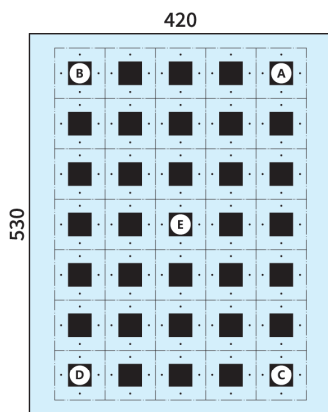
# TGV (ガラス貫通穴あけ) 基板 TGV (Through Glass Via)

大判ガラスに均一性のある  
高精度の穴あけを施します。

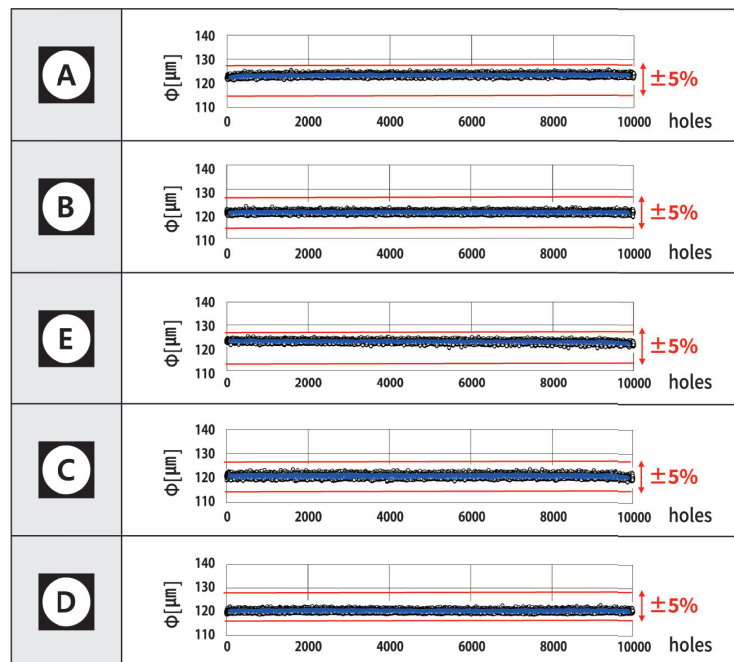
We can make through-hole vias in  
large-size glass with high precision  
and uniformity.

Specifications	
Substrate size	420 mm × 530 mm (0.4 mm t)
Number of holes	350,000 holes (10,000 holes × 35 faces)
Hole diameter	Φ120 μm (hourglass shape)

## 穴形状の均一性 Uniformity of hole shape

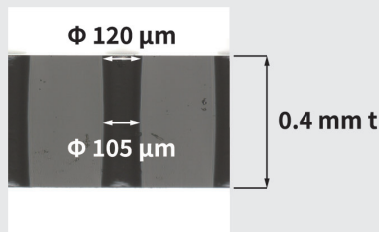


Overview: 10,000 holes × 35 faces



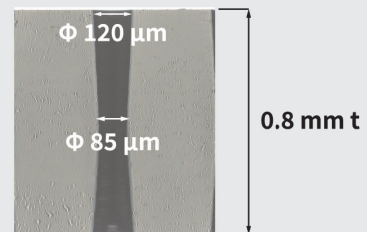
## 穴形状の垂直性 Perpendicularity of hole shape

Glass 0.4 mm t



Perpendicularity ..... **87%**

Glass 0.8 mm t



Perpendicularity ..... **70%**



# ミクロのTGV (ガラス貫通穴あけ) 加工基板 MICRO's TGV (through glass via) substrate

ガラス板厚と貫通穴径の実績データ (砂時計型)  
Actual data of glass thickness and through-hole via diameter (hourglass shape)

Diameter Thickness	Φ 150 μm	Φ 120 μm	Φ 100 μm	Φ 80 μm	Φ 60 μm	Φ 30 μm
t 0.1 mm						
t 0.2 mm						
t 0.4 mm						
t 0.5 mm						
t 0.8 mm						

ガラス素材別穴あけ加工比較  
Comparison of hole processing by glass material

Company T	Company C	Company N	Company S
<b>Synthetic quartz glass</b>	<b>Alkali free glass</b>	<b>Glass for Chemical strengthening</b>	<b>Heat resistant glass</b>
Hole diameter Φ50 μm	Hole diameter Φ120 μm	Hole diameter Φ120 μm	Hole diameter Φ120 μm
Glass thickness 0.7 mm	Glass thickness 0.4 mm	Glass thickness 0.4 mm	Glass thickness 0.4 mm

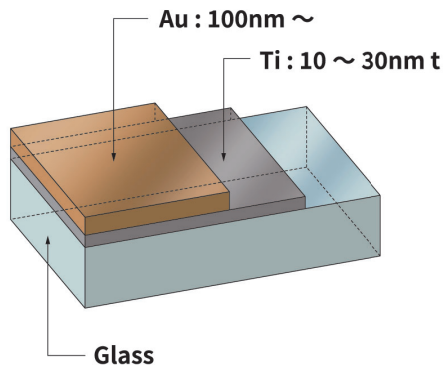


## TGVへの応用加工技術 Applied processing technologies for TGV substrates

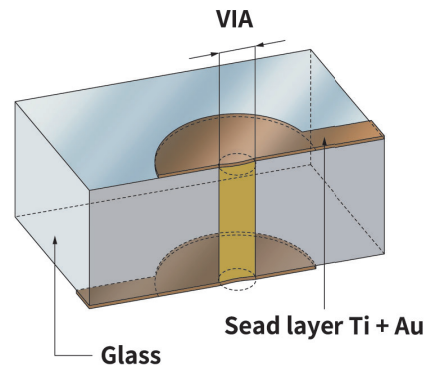
TGVへ金属薄膜加工と微細配線加工を施します。

We can apply metallic thin-film processing and micro wiring to a TGV substrate.

### スパッタリング法による金のシード層加工 Gold seed layer processing by sputtering method



### フォトリソグラフィ、エッチングによる金のパターン加工 Gold patterning by photolithography and etching



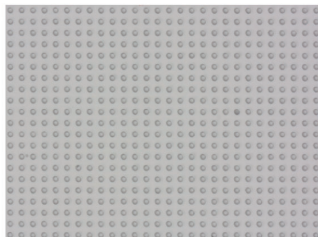
## ガラスの精密穴あけ加工 Precision hole processing in glass

ガラスへ様々な形状の精密な穴加工を施します。

We can make holes with various shapes in glass by precision processing.

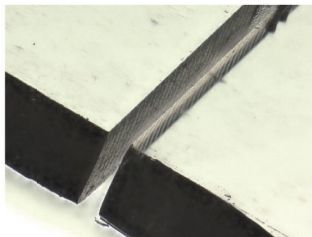
### 超精密穴あけ加工 Ultra-precision hole processing

φ50μmの穴を高精度で均一に加工を施します。  
High-precision uniform processing of holes of φ50 μm.



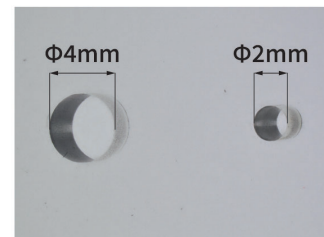
### 幅 100μm の長穴加工 100-μm-wide long-hole processing

幅 100μm × 長さ 2,000μm の長穴加工を施します。  
Processing of long holes of 100 μm wide and 2,000 μm long.



### 厚板ガラスへの穴加工 Thick-glass hole processing

ガラス厚み 2 mm にφ4 mm、φ2 mm、φ1 mmの精密な穴加工を施します。  
Precision processing of holes of φ4 mm, φ2 mm, and φ1 mm in 2-mm-thick glass



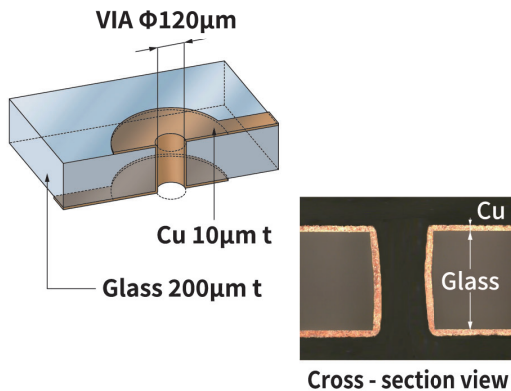
## ガラスの穴埋め電極加工 Hole-filling electrode processing in glass

ガラスの貫通穴への穴埋め電極加工を施します。

We can apply electrode processing to through-hole vias in glass by filling them.

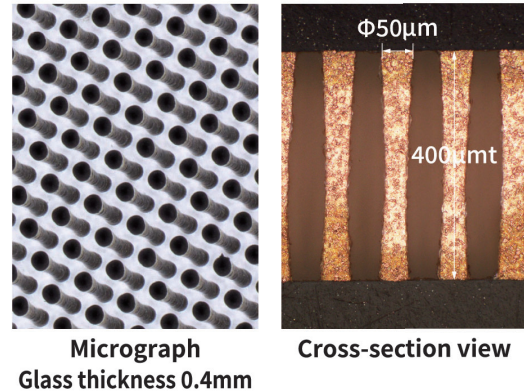
### コンフォーマル銅めっき穴埋め基板

Substrate with through-hole vias filled by conformal copper plating



### 銅ペースト穴埋め基板

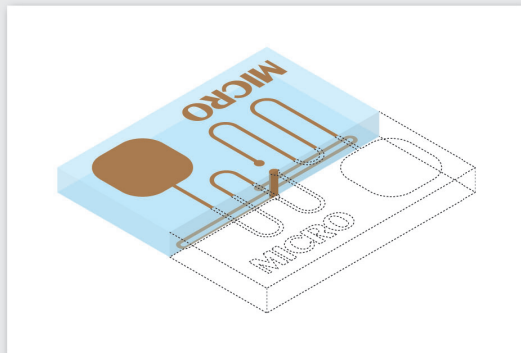
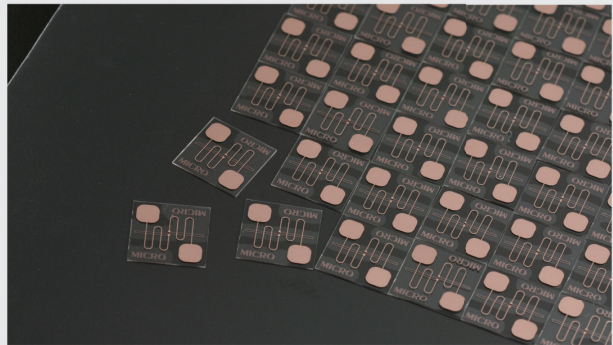
TGV filling with copper paste



## 薄板ガラス (0.2 mm t) への穴あけ両面配線部品 (10 mm sq.) Thin-glass part (0.2 mm t) with through-hole vias for double-sided wiring (10 mm sq.)

0.2 mm t の薄板ガラスに穴あけ加工と穴埋め加工を施し両面電極配線を可能にしたガラスです。

This is a thin-glass part fabricated by making through-hole vias in thin glass with a thickness of 0.2 mm and filling the through-hole vias, which enables double-sided electrode wiring.



### Specifications

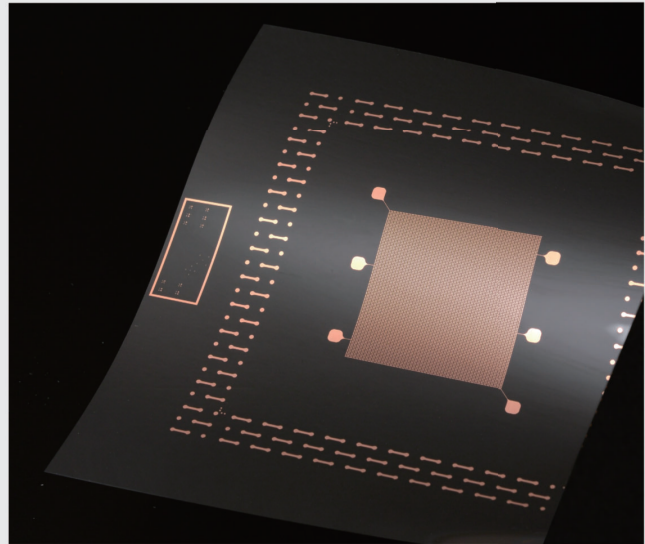
Substrate size	6 inch (150mm sq.)
Plate thickness	0.2 mm
Hole processing	$\Phi 100\mu\text{m}$
Wiring	<ul style="list-style-type: none"> <li>Seed layer : Ti</li> <li>Semi-additive copper plating, thickness: 10µm</li> </ul>
Hole filling	<ul style="list-style-type: none"> <li>Copper paste (fill type)</li> <li>Semi-additive copper plating, thickness: 10µm</li> </ul>



## 20 $\mu$ m 超薄板ガラスへの配線基板 20 $\mu$ m ultra-thin glass wiring substrate

マイクロ技術研究所は、超薄板ガラスをガラススリミングにより所定の厚みにする加工を得意としています。この度、ガラス厚20 $\mu$ mの超薄板ガラスに $\phi$ 50 $\mu$ mのスルーホール結合した両面配線基板を発表しました。スルーホールをフォトエッチングにより製作した関係でP-TGVと名付けました。

MICRO TECHNOLOGY specializes in processing of ultra-thin glass into specified thickness by chemical polishing. We have announced a double-sided wiring substrate fabricated by making 50- $\mu$ m-diameter through-hole vias for connection in ultra-thin glass with a thickness of 20  $\mu$ m. We have named the substrate P-TGV because its through-hole vias are fabricated by photo-etching.



## LCP樹脂フィルム配線基板 (液晶ポリマー) LCP (liquid crystal polymer) resin film wiring substrate



Specifications	
Adhesion	1kN/m or more
Maximum processing dimension	400 mm × 500mm
Film thickness	0.05 mm
Conductor thickness	Semi-additive copper plating, 5 $\mu$ m
Line width	L/S 20/20 $\mu$ m

